Icemos Technology Ltd Product Specification 1000.771501 Issue Date 19 March 2025 11:18:

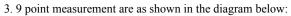
Part Number	Customer	
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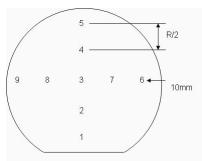
Category		Parameter	Specification	Measurement Method
OverallWafer	1.0	Diameter	150.00 +/- 0.50 mm	
	2.0	Primary Flat Orientation	{110} +/- 1.0 degree	Wafer Vendor
	3.0	Primary Flat Length	57.50 +/- 2.50 mm	Wafer Vendor
	4.0	Secondary Flat Orientation	none	Wafer Vendor
	5.0	Overall Thickness	431.00 +/- 26.00 μm	ADE, 100%
	6.0	Total Thickness Variation (TTV)	<5.00μm	Guaranteed by Process
	7.0	Bow	<100.00μm	ADE to ASTM F534, 100%
	8.0	Warp	<100.00μm	
	9.0	Edge Chips	0	Bright Light, 100% (note 2)
	10.0	Edge Exclusion	5mm	
HandleSilicon	11.0	Handle Growth Method	CZ	Wafer Vendor
	12.0	Handle Orientation	{100} +/- 0.5 degree	Wafer Vendor
	13.0	Handle Thickness	300.00 +/- 25.00 μm	ADE, 100%
	14.0	Handle Doping Type	N	Wafer Vendor
	15.0	Handle Dopant	Phos	Wafer Vendor
	16.0	Handle Resistivity	0.003-0.01 Ohm-cm	Wafer Vendor
	17.0	Backside Finish	Polished with oxide, lasermark, and light handling marks	Guaranteed by process
BuriedOxide	18.0	Oxide Type	Thermal	
	19.0	Oxide Thickness	10,000.00 +/- 500.00 A	Nanospec centre point, 4%
	20.0	Oxide formed on	Handle and / or Device wafer	Graranteed by process
DeviceSilicon	21.0	Device Growth Method	CZ	Wafer Vendor
	22.0	Device Orientation	{100} +/- 0.5 degree	Wafer Vendor
	23.0	Nominal Thickness	130.00 +/- 1.00 μm	ADE, Single-point, 100%
	24.0	Distance to device silicon edge from wafer edge	<= 2mm	Guaranteed by process
	25.0	Device Doping Type	N	Wafer Vendor
	26.0	Device Dopant	Phos	Wafer Vendor
	27.0	Device Resistivity	0.003-0.01 Ohm-cm	Wafer Vendor
	28.0	Voids	none	Bright Light, 100% (note 2)
	29.0	Scratches	0	Bright Light, 100% (note 2)
	30.0	Haze	none	Bright Light, 100% (note 2)

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Part Number		Customer	
Category	Parameter	Specification	Measurement Method
Shipping Details	Wafer per box :	Max 25	
	Packaging:	Taped Polypropylene Wafer Box Empak, Ultrapak, 150.00mm Antistatic Double Bagging	
	Lot Shipment Data	Device Thickness Bow / Warp Data Handle and SOI Thickness	
Explanatory Notes	1. Microscope inspec	ction performed using microscope scan as below. 5x objective.	
		pections performed exclude all wafer area outside the edge exclusion	on defined in Overall

2. All bright light inspections performed exclude all wafer area outside the edge exclusion defined in Overal Wafer, Edge Exclusion. High intensity bright lamp inspection as per ASTM F523.





Additional Information